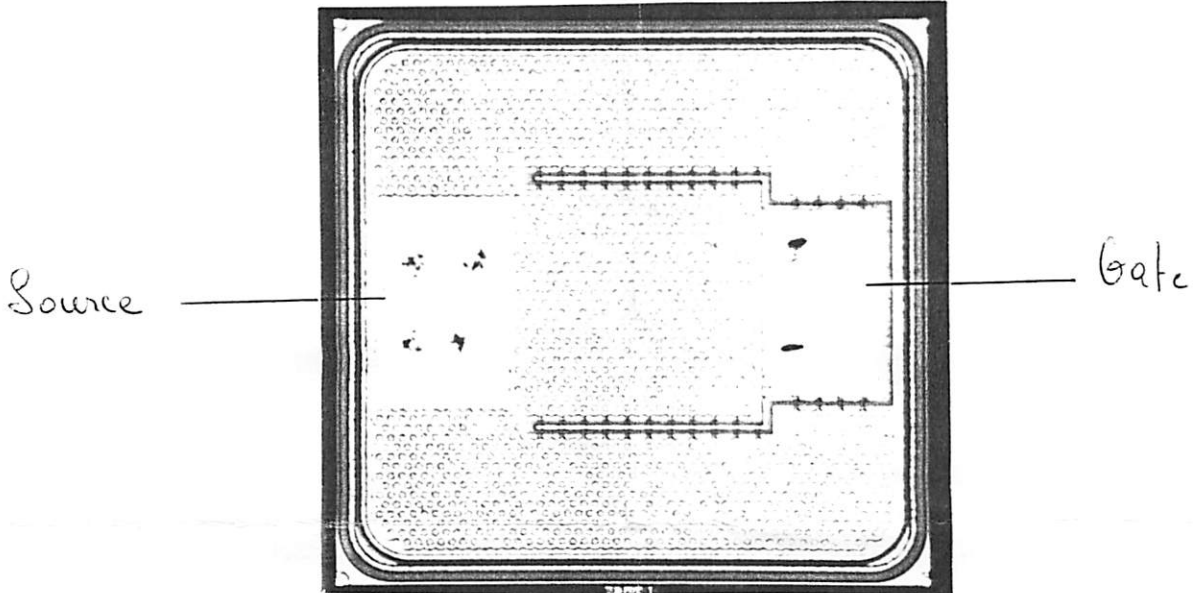

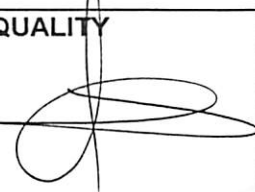


DEVICE: IRF9210		MANUFACTURER: IR	
CATEGORY: TRANSISTOR		PROCESS: —	
FUNCTION: P CHANNEL		MASK N°: —	
DIE THICKNESS: —	DIE SIZE: 2,15 X 2,05		MM ² / 85 X 81 Mils
FRONT SIDE: ALU		BACK SIDE: cr/ni/ag	
GLASSIVATION: YES	NO	SUBSTRATE POTENTIAL: DRAIN	



ATTENTION
 Static Sensitive
 Devices
 Handle Only at
 Static Safe Work
 Stations.

PAD IDENTIFICATION	PAD IDENTIFICATION	PAD IDENTIFICATION	PAD IDENTIFICATION
01-	11-	21-	31-
02-	12-	22-	32-
03-	13-	23-	33-
04-	14-	24-	34-
05-	15-	25-	35-
06-	16-	26-	35-
07-	17-	27-	37-
08-	18-	28-	38-
09-	19-	29-	39-
10-	20-	30-	40-

	DESIGN	MANUFACTURING	QUALITY
	NAME A. Bumeau	NAME	NAME
	DATE 08.03.87.	DATE	DATE
VISA: AB-	VISA:	VISA	

REVISION: A	GEOMETRY N°: 3031
ELMO Semiconducteurs	GEOMETRY DRAWING
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